Electronic Pate	nt App	lication Fee	: i ransm	ittal			
Application Number:	105	10549784					
Filing Date:	10-	10-Jul-2006					
Title of Invention:	CH	SEMICONDUCTOR STRUCTURE COMPRISING A HIGHLY DOPED CONDUCTIV CHANNEL REGION AND METHOD FOR PRODUCING A SEMICONDUCTOR STRUCTURE					
First Named Inventor/Applicant Name:	Ruc	Rudolf Elpelt					
Filer:	Ral	Ralph Eric Locher/Sabriye Avery					
Attorney Docket Number:	S4-	S4-01P16203					
Filed as Large Entity	•						
U.S. National Stage under 35 USC 371 Fil	ing Fee	5					
Description		Fee Code	Quantity	Amount	Sub-Total in USD(\$)		
Basic Filing:							
Pages:							
Claims:							
Miscellaneous-Filing:							
Petition:							
Patent-Appeals-and-Interference:							
Post-Allowance-and-Post-Issuance:							
Utility Appl issue fee		1501	1	1510	1510		

Publ. Fee- early, voluntary, or normal

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)
Extension-of-Time:				
Miscellaneous:				
	Total in USD (\$)			1810